(Unit : mm)

GH5RA1HA3C

(Under development)

Features

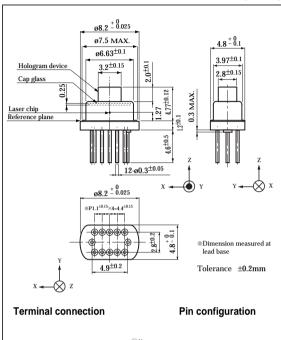
- (1) High power output (pulse MAX. 144mW)
- (2) For ×16 speed CD-R, ×40 speed CD-ROM (With built-in MIN. 45MHz OPIC*)
- (3) Sample hold system (tracking method)
- (4) High coupling efficiency $\label{eq:effciency} The ellipticity \; (\theta \bot / \theta / /) \; is \; close \; to \; 1.$
- (5) \$\$4.8mm thickness
- (6) With built-in beam splitter and diffraction grating
 - *OPIC : (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and a signal-processing circuit integrated onto a single chip.

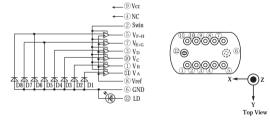
Applications

- (1) CD-R drives
- (2) CD-RW drives

Sampling Hold Method, High Power Output Hologram Laser for X16 Speed CD-R Drive

Outline Dimensions





	(IC=25 C)			
Para	neter	Symbol	Rating	Unit
*1 Optical power out	put	Рнс	101	mW
*2 Optical power out	put (pulse)	Рнр	144	mW
Reverse voltage	Laser	VR	2	v
OPIC supply volta	ge	Vcc	6	v
*3 Operating temper	Topr	0 to +60	°C	
*3 Storage temperate	Tstg	-40 to +85	°C	
*4 Soldering temperative	ature	Tsold	260	°C

*1 Output power from hologram laser Equivalent to 120mW (CW) from cap glass

Output power from hologram laser Equivalent to 160mW (pulse) from cap glass (pulse width : 0.5µs, Duty : 50%)

*3 Case temperature *4 At the position of 1.6mm from the lead base (Within 5s)

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Absolute Maximum Ratings

(Tc=25°C)

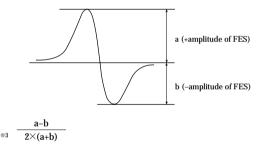
 $(T_{c-}95^{\circ}C)$

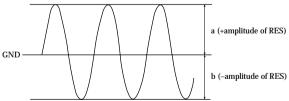
Electro-optical Characteristics

Electro-optical Charact	teristics					(1c=25C)
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*1 Focal offset	DEF	Collimated lens output power 1.5mW, High gain	-0.7	-	+0.7	μm
*2 Focal error symmetry	Bres	Collimated lens output power 1.5mW, High gain	-25	-	+25	%
^{*3} Radial error balance	Bres	Collimated lens output power 1.5mW, High gain	-25	-	+25	%
*4 RF output amplitude	Vrfh	Collimated lens output power 1.5mW, High gain	0.32	0.47	0.62	v
^{\$5} FES output amplitude	VFES	Collimated lens output power 1.5mW, High gain	0.17	0.3	0.47	v
^{*6} RES output amplitude	Vres	Collimated lens output power 1.5mW, High gain	0.04	0.1	0.15	v
^{*7} Main spot balance	MSB	Collimated lens output power 1.5mW, High gain	80	(100)	120	%
^{**8} Sub spot balance	SSB	Collimated lens output power 1.5mW, High gain	80	(100)	120	%
Jitter	JIT	Collimated lens output power 1.5mW, High gain	-	-	23	ns
^{*9} Strain of RF signal shape	RFh	Collimated lens output power 1.5mW, High gain	-	-	230	%

 \ast1 Distance between FES=0 and jitter minimum point

**2 (a-b) / (a+b)



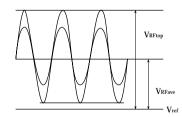


^{®4} Amplitude of V_A+V_B+V_C+V_D (focal servo ON, radial servo ON)

*5 VB-VA (Focal vibration)

^{@6} Amplitude of (Vc-Vp)-k1(VE+G-VF+H). k1=(Vc+Vp)/(VE+G+VF+H)=1 When tracking servo is ON, (Vc-Vp)-k1(VE+G-VF+H)+ α should be 0.

- *7 (VA+VB) / (VC+VD)
- *8 Vc/VD
- *9 VRFtop/VRFave



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Electro-optical Characteristics of Laser Diode (Tc=25°C) Parameter Symbol Conditions MIN. TYP. MAX. Unit Threshold current Ith 30 41 mA Operating current Iop Po=100mW 130 155 mA Operating voltage Vop Po=100mW 2.2 2.5 v -Wavelength λ_p Po=100mW 773 784 797 nm 70mW Differential efficiency 0.7 0.85 mW/mA ηd 1.2 I(100mW)-I(30mW) Stability of differential efficiency $\Delta\eta_d$ Po=10 to 150mW 40 % . . 0 Parallel $\theta / /$ 7.5 9 10.5 Half intensity angle Perpendicular $\theta \perp$ 14.5 17 19.5 Po=100mW Emission Deviation Parallel ø// -2 +2characteristics angle Perpendicular ø⊥ -3 +30 Beam shift $\Delta \mathbf{g} / /$ ø//(100mW)-ø//(3mW) -1 +1 K-LI1 Po=10 to 150mW 0.988 % . Kink K-LI2 P1=30mW, P2=90mW, P3=150mW 15 %

Electro-optical Characteristics of OPIC for Signal Detection^{*10}

(Tc=25°C, Vcc=5V, Vref=2.1V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	*11 Segment
Supply current	Icc1	High gain, Gain switching SW=H	-	20	25	mA	
	ICC2	Low gain, Gain switching SW=L	-	30	35	mA	
*12 Output off-set voltage	Vod	Common to high/low gain, No light	-25	2	+25	mV	A, B
Off-set voltage difference, Gain switching	ΔV_{od}	Common to high/low gain	-30	-	+30	mV	A, B

^{e10} 0.1µF or more capacitor should be added between OPIC power supply terminal and GND, Vref terminal and GND. (at the position of 5mm or less from the lead base)

*11 Applicable divisions correspond to output terminals.

A : VA, VB, VC, VD

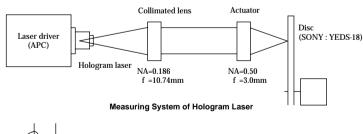
B : Ve+g, Vf+h

*12 Difference from Vref

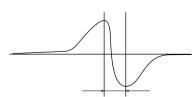
■ Electro-optical Characteristics of Hologram Laser (Design Standard*)*1 (Tc=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*2 Focal error signal capture range	-	-	-	14	-	μm
Focal error signal sensitivity	-	-	-	13	-	%∕µm

*1



*2



* These parameters are not guaranteed performance, but general specifications of each optical element which makes up a hologram laser.

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Optical Charact	eristics of H	ologram	Device (Design Standard*)				(Tc=25°C)
Paramete	r	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Hologram diffraction	0 th	-	λ=780nm	77	82	-	%
efficiency	±1st	-		6	7	9	%
Hologram diffraction	D1,D2	-	λ=780nm	-	21.1	-	۰
angle	Except D1,D2	-		-	26.4	-	۰
Grating diffraction effi	ciency	-	0:1	6.7	9	12.4	-
Grating diffraction ang	gle	-	λ=780nm	-	2.8	-	•

 Electro-optical Characteristics of Laser Diode (Design Standard*) 						(Tc=25°C)
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
	$\Delta \mathbf{x}$		-80	-	+80	μm
Misalignment position	Δy	_	-80	-	+80	μm
	Δz		-80	-	+80	μm
*3 Reflectivity of LD rear facet	Rr	_	85	-	-	%

Electro-optical Characteristics of OPIC for Signal Detection (Design Standard*)

(Tc=25°C, Vcc=5V, Vref=2.1V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	*4 Segment
Supply voltage	Vcc	-	4.75	5	5.25	V	
Reference voltage	Vref	-	2.00	2.1	2.21	V	
	fcm	Common to high/low gain, -3dB	45	60	-	MHz	Α
*6.7.8.9 Response frequency	fcsH	Sub amp, Hign gain, -3dB	1	2	-	MHz	В
	fcsL	Sub amp, Low gain, -3dB	16	24	-	MHz	В
*568.9 Peaking level	Vpk2	Common to high/low gain f=0.1 to 50MHz	-	-	3	dB	A
*9 Noise level	fnm	Hign gain, 50 Ω end BW=30kHz, f=36MHz	-	-74	-70	dBm	A
Sensitivity 1	R _m 1	Main amp, Hign gain	9	12	15	mV/µW	A
Sensitivity 2	Rm2	Main amp, Low gain	2.25	3	3.75	mV/µW	A
Sensitivity 3	R _m 3	Sub amp, Hign gain	36	48	60	mV/µW	В
Sensitivity 4	R _m 4	Sub amp, Low gain	9	12	15	mV/µW	В
Thermal drift of sensitivity	R _{sm} /T	Common to high/low gain	-	4 200	-	ppm/°C	A, B
Thermal drift of offset voltage	Vod/T	Common to high/low gain, No light	-	300	-	µV/°C	A, B
Thermal drift of offset voltage 1	Vos1/T	Main amp, Hign gain, No light	-	30	-	µV/°C	A
Thermal drift of offset voltage 2	Vos2/T	Main amp, Low gain, No light	-	25	-	µV/°C	A
Thermal drift of offset voltage 3	Vos3/T	Sub amp, Hign gain, No light	-	30	-	µV/°C	В
Thermal drift of offset voltage 4	Vos4/T	Sub amp, Low gain, No light	-	25	-	µV∕°C	В
Thermal drift of offset voltage 5	Vos5/T	Between main-sub amp, Hign gain, No light	-	100	-	µV/°C	A-B
Thermal drift of offset voltage 6	Vos6/T	Between main-sub amp, Low gain, No light	-	75	-	µV/°C	A-B
Stabilization time at gain switching	tstr2	Common to high/low gain, time for ±3mV	-	-	25	μs	A, B
Sottling time	testm	$500 mV \rightarrow 10 mV \qquad f{=}6.9 MHz$	-	30	-	ns	Α
Settling time	tests	Low gain, fall time f=3.1MHz	-	90	-	ns	В
Maximum output voltage	V _o max	Common to high/low gain, Vref reference	1	-	-	V	A, B

*3 Sampling rate is 1pc./reflection membrane formation process lot 4 Appriable divisions correspond to output torminals

Appricable divisions correspond to output terminals.

A : VA, VB, VC, VD

B : VE+G, VF+H Difference from Vref

^{*6} Light source is a laser diode of λ =780nm.

 $^{\circ7}$ -3dB level (0dB level is taken for output level when f=0.1MHz) $^{\circ8}$ 10 μW of DC light is applied to the center of each photodiode, and $4\mu W$ of AC light is irradiated. BW=10kHz

⁹⁹ 5kΩ of resistor and 10pF of capacitor should be connected in parallel between output terminal and Vref terminal.

* These parameters are not guaranteed performance, but general specifications of each optical element which makes up a hologram laser.
Please refer to the chapter "Handling Precautions"

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- --- Office automation equipment
- --- Telecommunication equipment [terminal]
- --- Test and measurement equipment
- --- Industrial control
- --- Audio visual equipment
- --- Consumer electronics

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- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.

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- --- Telecommunication equipment [trunk lines]
- --- Nuclear power control equipment

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